

1. General description

NPN low V_{CEsat} transistor, encapsulated in an ultra thin SOT1061D (DFN2020D-3) leadless small Surface-Mounted Device (SMD) plastic package with medium power capability and side-wettable flanks (SWF).

2. Features and benefits

- Very low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High collector current gain (h_{FE}) at high I_C
- High efficiency due to less heat generation
- High temperature applications up to 175 °C
- Reduced Printed-Circuit Board (PCB) area requirements
- Leadless small SMD plastic package with soldarable side pads
- · Exposed heat sink for excellent thermal and electrical conductivity
- Suitable for Automatic Optical Inspection (AOI) of solder joint
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Linear voltage regulation
- Loadswitch
- Battery-driven devices
- Power management
- Charging circuits
- Power switches (e.g. motors, fans)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	N	lin	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-		-	10	V
I _C	collector current		-		-	3	А
h _{FE}	DC current gain	V_{CE} = 2 V; I _C = 100 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	3	25	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = 1 A; I_B = 10 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-		-	55	mV

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5. Pinning information

Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	В	base	3				
2	E	emitter		С			
3	C	collector	I 2 Transparent top view DFN2020D-3 (SOT1061D)	B			

6. Ordering information

Table 3.	Ordering	information	1

Type number			
	Name	Description	Version
PBSS4310PAS-Q	DFN2020D-3	plastic, leadless thermal enhanced ultra thin small outline package with side-wettable flanks (SWF); no leads; 3 terminals; 1.3 mm pitch; 2 mm x 2 mm x 0.65 mm body	<u>SOT1061D</u>

7. Marking

Table 4. Marking codes				
Type number	Marking code			
PBSS4310PAS-Q	F2			

8. Limiting values

Table 5. Limiting values

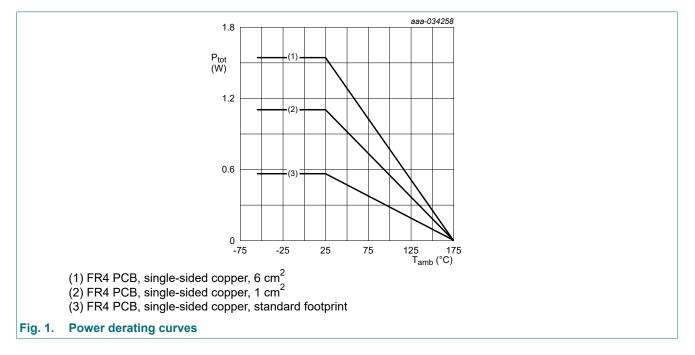
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	10	V
V _{CEO}	collector-emitter voltage	open base		-	10	V
V _{EBO}	emitter-base voltage	open collector		-	8	V
l _C	collector current			-	3	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	5	А
I _B	base current			-	500	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	560	mW
			[2]	-	1.1	W
			[3]	-	1.54	W
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint. [1]

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm². Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm². [2]

[3]



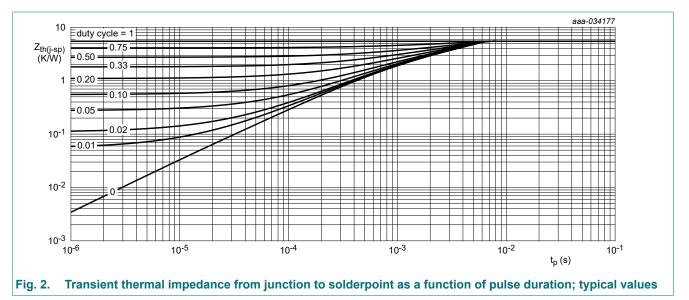
9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	[1]	-	-	268	K/W
	junction to ambient		[2]	-	-	137	K/W
			[3]	-	-	98	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	7	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².



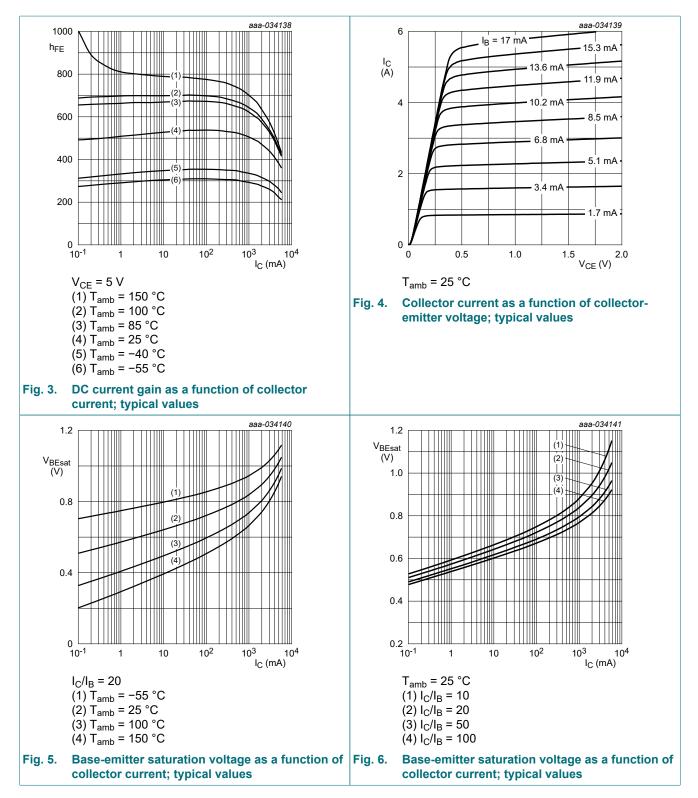
10. Characteristics

Table 7. Characteristics						
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{(BR)CBO}	collector-base breakdown voltage	I _C = 100 μA; I _E = 0 A	10	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = 10 mA; I _B = 0 A	10	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage	I _E = 100 μA; I _C = 0 A	8	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = 8 V; I _E = 0 A; T _{amb} = 25 °C	-	-	100	nA
		V _{CB} = 8 V; I _E = 0 A; T _j = 125 °C	-	-	50	μA
I _{CES}	collector-emitter cut-off current	V _{CE} = 8 V; V _{BE} = 0 V; T _{amb} = 25 °C	-	-	100	nA
I _{EBO}	emitter-base cut-off current	V _{EB} = 6.4 V; I _C = 0 A; T _{amb} = 25 °C	-	-	100	nA

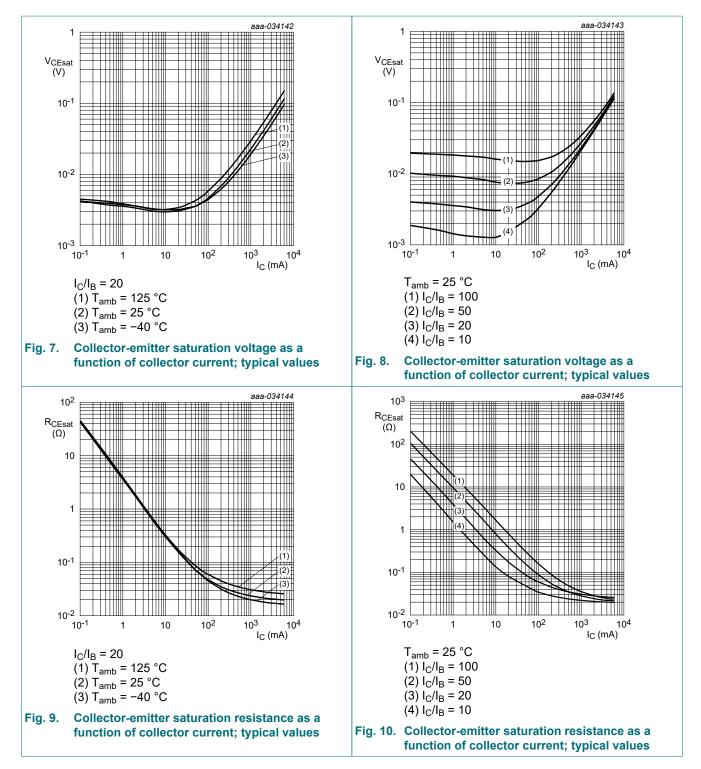
10 V, 3 A NPN low VCEsat transistor

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
h _{FE}	DC current gain	V_{CE} = 2 V; I _C = 100 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	325	-	-	
		$ V_{CE} = 2 \text{ V; } I_C = 500 \text{ mA; pulsed; } t_p \leq \\ 300 \mu\text{s; } \delta \leq 0.02\text{; } T_{amb} = 25 ^\circ\text{C} $	325	-	-	
		$ V_{CE} = 2 \text{ V}; I_{C} = 1 \text{ A}; \text{ pulsed}; t_{p} \leq 300 \mu\text{s}; \\ \delta \leq 0.02; T_{amb} = 25 ^{\circ}\text{C} $	300	-	-	
		$ V_{CE} = 2 \text{ V; } I_C = 2 \text{ A; pulsed; } t_p \le 300 \mu\text{s;} \\ \delta \le 0.02; T_{amb} = 25 ^\circ\text{C} $	275	-	-	
		$ V_{CE} = 2 \text{ V}; I_C = 3 \text{ A}; \text{ pulsed}; t_p \leq 300 \mu\text{s}; \\ \delta \leq 0.02; T_{amb} = 25 ^\circ\text{C} $	250	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = 500 mA; I_B = 50 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	25	mV
		I_{C} = 1 A; I_{B} = 50 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	35	mV
		I_C = 1 A; I_B = 10 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	55	mV
		I_{C} = 2 A; I_{B} = 20 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	85	mV
		$I_C = 3$ A; $I_B = 150$ mA; pulsed; $t_p \le 300$ μs; $\delta \le 0.02$; $T_{amb} = 25$ °C	-	-	90	mV
		I_C = 3 A; I_B = 30 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	110	mV
V _{BEsat}	base-emitter saturation voltage	I _C = 1 A; I _B = 100 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	-	1	V
		I _C = 3 A; I _B = 300 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	-	1.2	V
V _{BEon}	base-emitter turn-on voltage	$ V_{CE} = 2 \text{ V}; I_{C} = 2 \text{ A}; \text{ pulsed}; t_{p} \leq 300 \mu\text{s}; \\ \delta \leq 0.02; T_{amb} = 25 ^{\circ}\text{C} $	-	-	845	mV
t _d	delay time	I _C = 2 A; I _{Bon} = 100 mA; I _{Boff} = -100 mA;	-	16	-	ns
t _r	rise time	T _{amb} = 25 °C	-	55	-	ns
t _s	storage time		-	190	-	ns
t _f	fall time		-	48	-	ns
f _T	transition frequency	V _{CE} = 5 V; I _C = 100 mA; f = 100 MHz; T _{amb} = 25 °C	-	80	-	MHz
C _c	collector capacitance	V_{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	75	-	pF

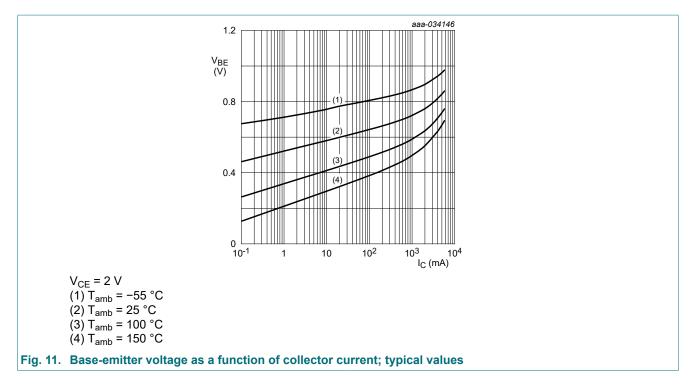
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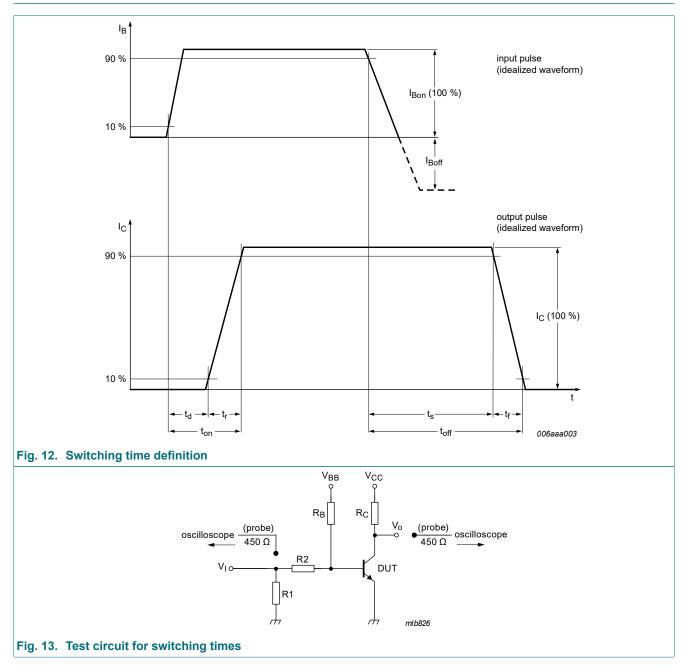


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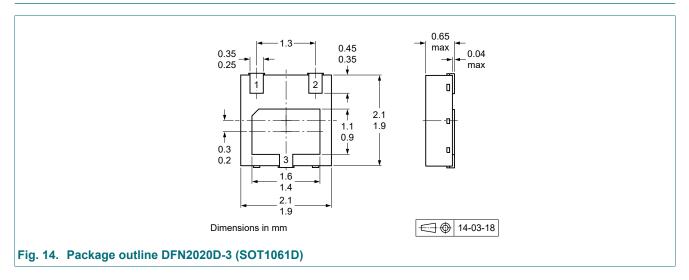
11. Test information



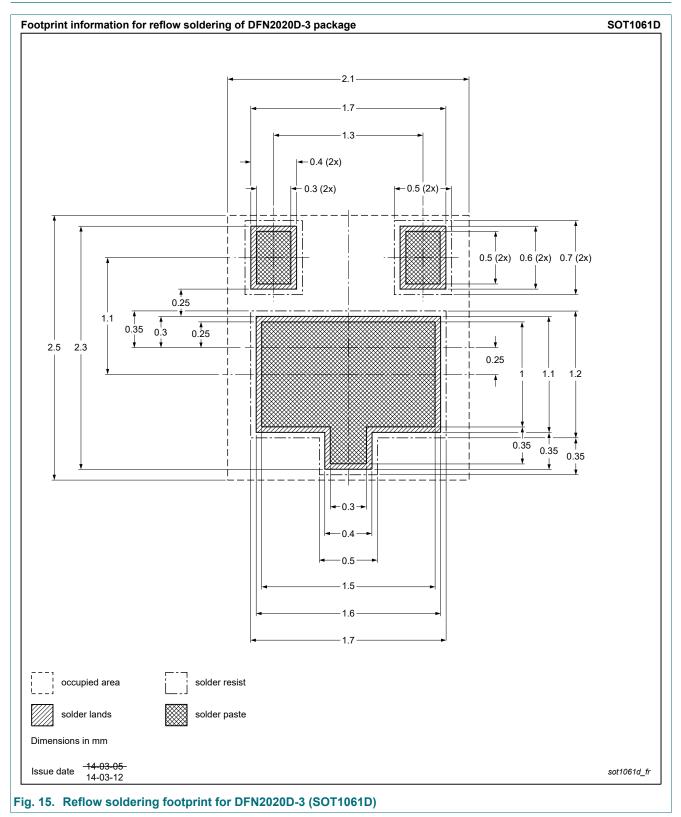
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



13. Soldering



14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PBSS4310PAS-Q v.4	20241220	Product data sheet	-	PBSS4310PAS-Q v.3			
Modifications:	Characteristics: Grap	Characteristics: Graphs in figures 7 and 9 corrected					
PBSS4310PAS-Q v.3	20220121	Product data sheet	-	PBSS4310PAS-Q v.2			
PBSS4310PAS-Q v.2	20211215	Product data sheet	-	PBSS4310PAS-Q v.1			
PBSS4310PAS-Q v.1	20211203	Preliminary data sheet	-	-			

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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